

MOSFET – N-Channel, POWERTRENCH®

80 V, 65 A, 7.5 mΩ

FDMS86369-F085

Features

- Typ $R_{DS(on)}$ = 5.9 mΩ at $V_{GS} = 10$ V; $I_D = 65$ A
- Typ $Q_{g(tot)}$ = 35 nC at $V_{GS} = 10$ V; $I_D = 65$ A
- UIS Capability
- AEC-Q101 Qualified and PPAP Capable
- This Device is Pb-Free, Halogen Free/BFR Free and is RoHS Compliant

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12 V Systems

MOSFET MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

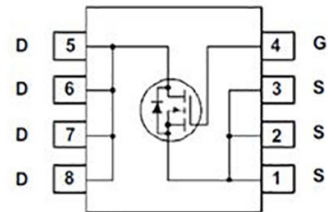
Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSS}	80	V
Gate-to-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ($V_{GS} = 10$ V) (Note 1)	I_D	65	A
Pulsed Drain Current	$T_C = 25^\circ\text{C}$	See Figure 4	
Single Pulse Avalanche Energy (Note 2)	E_{AS}	27	mJ
Power Dissipation	P_D	107	W
Derate above 25°C		0.71	W/ $^\circ\text{C}$
Operating and Storage Temperature	T_J, T_{STG}	-55 to $+175$	$^\circ\text{C}$
Thermal Resistance (Junction-to-Case)	$R_{\theta JC}$	1.4	$^\circ\text{C/W}$
Maximum Thermal Resistance (Junction-to-Ambient) (Note 3)	$R_{\theta JA}$	50	$^\circ\text{C/W}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

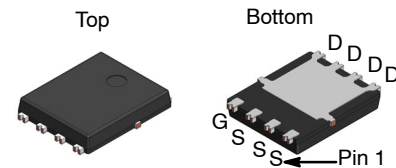
1. Current is limited by bondwire configuration.
2. Starting $T_J = 25^\circ\text{C}$, $L = 20$ μH, $I_{AS} = 52$ A, $V_{DD} = 80$ V during inductor charging and $V_{DD} = 0$ V during time in avalanche.
3. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2 oz copper.

V_{DSS}	$R_{DS(on)}$ MAX	I_D MAX
80 V	7.5 mΩ @ 10 V	65 A

ELECTRICAL CONNECTION

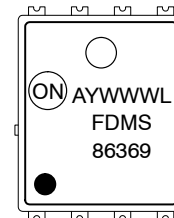


N-Channel MOSFET



DFNW8
CASE 507AU

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
WL = Assembly Lot
FDMS86369 = Specific Device Code

ORDERING INFORMATION

Device	Package	Shipping†
FDMS86369-F085	DFNW8 (Power 56) (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

B_{VDSS}	Drain-to-Source Breakdown Voltage	$I_D = 250\ \mu\text{A}$, $V_{GS} = 0\ \text{V}$	80	–	–	V
I_{DSS}	Drain-to-Source Leakage Current	$V_{DS} = 80\ \text{V}$, $V_{GS} = 0\ \text{V}$	$T_J = 25^\circ\text{C}$	–	–	1 μA
			$T_J = 175^\circ\text{C}$ (Note 4)	–	–	1 mA
I_{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20\ \text{V}$	–	–	± 100	nA

ON CHARACTERISTICS

$V_{GS(th)}$	Gate-to-Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250\ \mu\text{A}$	2.0	3.0	4.0	V
$R_{DS(on)}$	Drain-to-Source On-Resistance	$I_D = 65\ \text{A}$, $V_{GS} = 10\ \text{V}$	$T_J = 25^\circ\text{C}$	–	5.9	7.5 $\text{m}\Omega$
			$T_J = 175^\circ\text{C}$ (Note 4)	–	12.2	15.5

DYNAMIC CHARACTERISTICS

C_{iss}	Input Capacitance	$V_{DS} = 40\ \text{V}$, $V_{GS} = 0\ \text{V}$, $f = 1\ \text{MHz}$	–	2470	–	pF
C_{oss}	Output Capacitance		–	400	–	
C_{rss}	Reverse Transfer Capacitance		–	14	–	
R_g	Gate Resistance	$f = 1\ \text{MHz}$	–	1.8	–	Ω
$Q_{g(tot)}$	Total Gate Charge	$V_{GS} = 0\ \text{to}\ 10\ \text{V}$	$V_{DD} = 64\ \text{V}$, $I_D = 65\ \text{A}$	–	35	46 nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0\ \text{to}\ 2\ \text{V}$		–	4.5	–
Q_{gs}	Gate-to-Source Gate Charge			–	12.5	–
Q_{gd}	Gate-to-Drain “Miller” Charge			–	8	–

SWITCHING CHARACTERISTICS

t_{on}	Turn-On Time	$V_{DD} = 40\ \text{V}$, $I_D = 65\ \text{A}$, $V_{GS} = 10\ \text{V}$, $R_{GEN} = 6\ \Omega$	–	–	39	ns
$t_{d(on)}$	Turn-On Delay		–	15	–	
t_r	Rise Time		–	11	–	
$t_{d(off)}$	Turn-Off Delay		–	24	–	
t_f	Fall Time		–	8	–	
t_{off}	Turn-Off Time		–	–	48	

DRAIN-SOURCE DIODE CHARACTERISTICS

V_{SD}	Source-to-Drain Diode Voltage	$I_{SD} = 65\ \text{A}$, $V_{GS} = 0\ \text{V}$	–	–	1.4	V
		$I_{SD} = 32.5\ \text{A}$, $V_{GS} = 0\ \text{V}$	–	–	1.2	
t_{rr}	Reverse Recovery Time	$I_F = 65\ \text{A}$, $dI_{SD}/dt = 100\ \text{A}/\mu\text{s}$, $V_{DD} = 64\ \text{V}$	–	49	74	ns
Q_{rr}	Reverse Recovery Charge		–	44	68	nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. The maximum value is specified by design at $T_J = 175^\circ\text{C}$. Product is not tested to this condition in production

TYPICAL CHARACTERISTICS

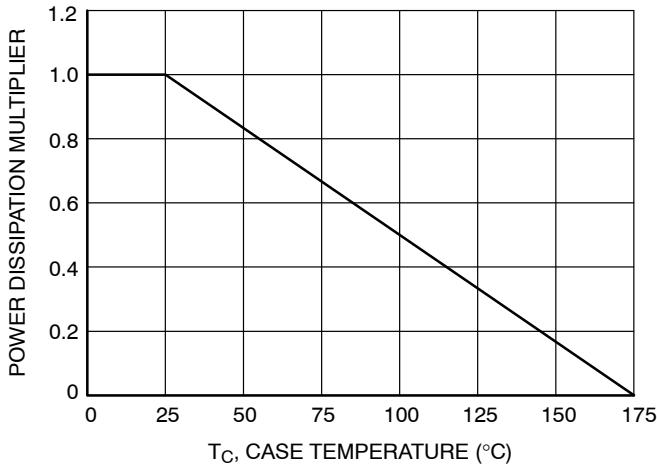


Figure 1. Normalized Power Dissipation vs. Case Temperature

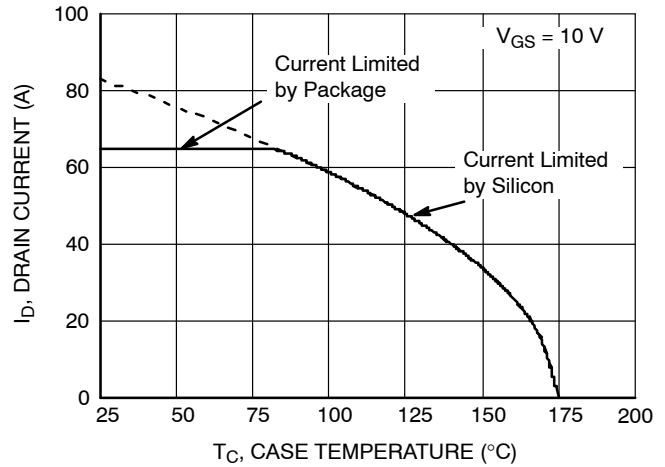


Figure 2. Maximum Continuous Drain Current vs. Case Temperature

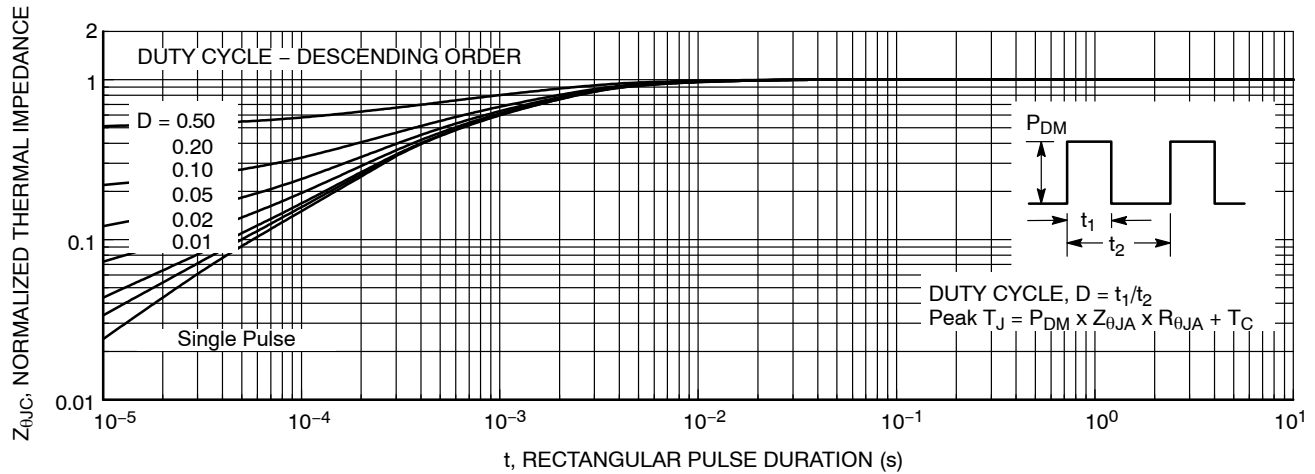


Figure 3. Normalized Maximum Transient Thermal Impedance

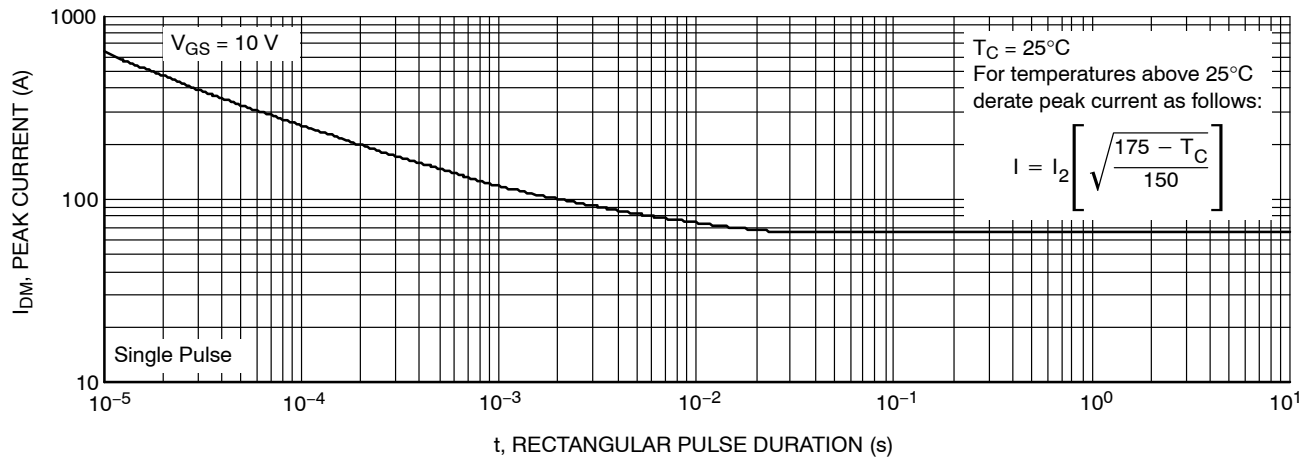


Figure 4. Peak Current Capability

TYPICAL CHARACTERISTICS (continued)

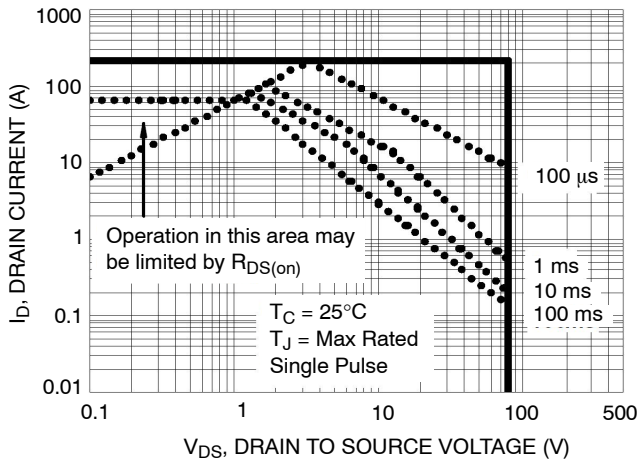


Figure 5. Forward Bias Safe Operating Area

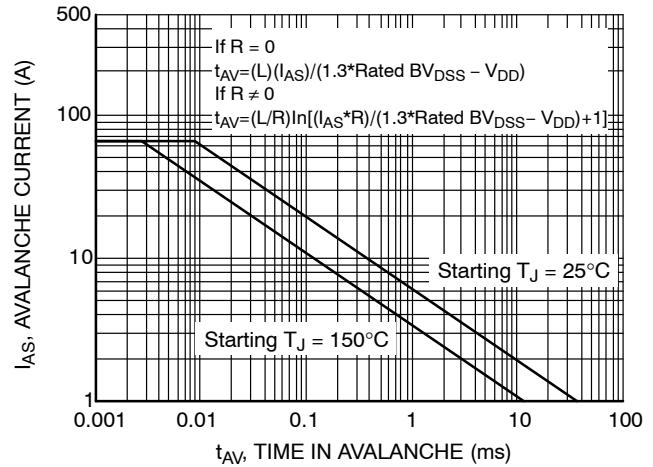


Figure 6. Unclamped Inductive Switching Capability

(Note: Refer to onsemi Applications Notes [AN7514](#) and [AN7515](#))

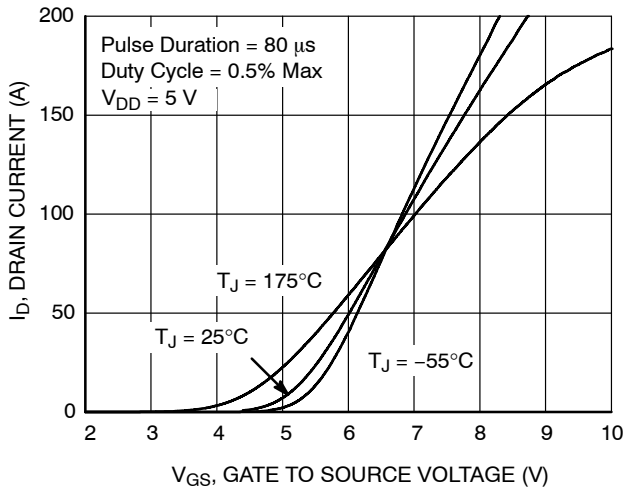


Figure 7. Transfer Characteristics

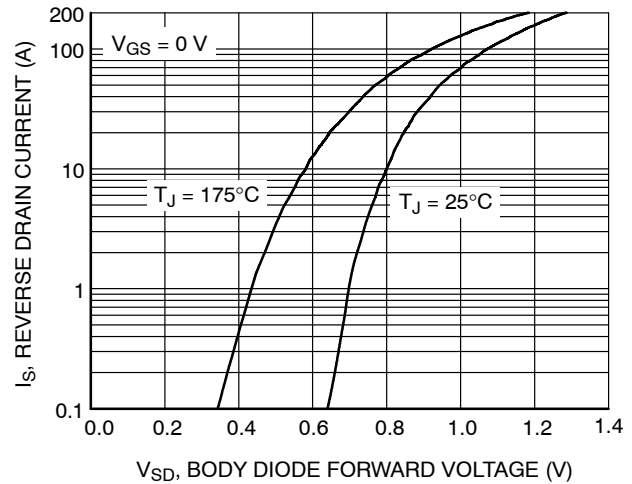


Figure 8. Forward Diode Characteristics

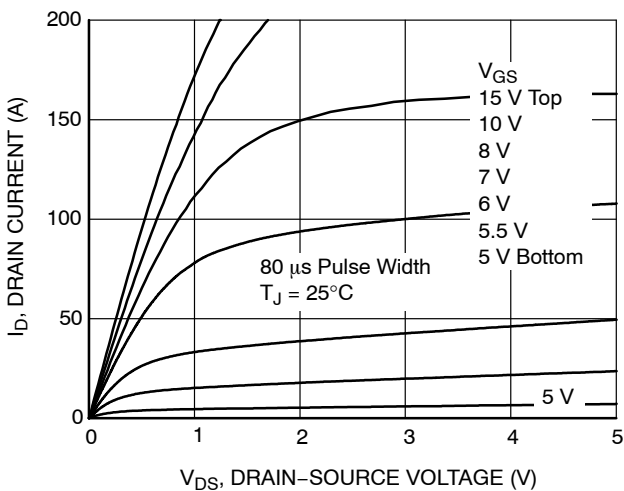


Figure 9. Saturation Characteristics

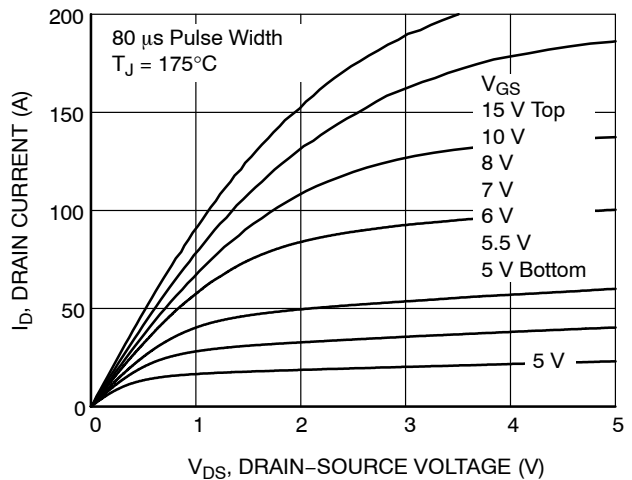
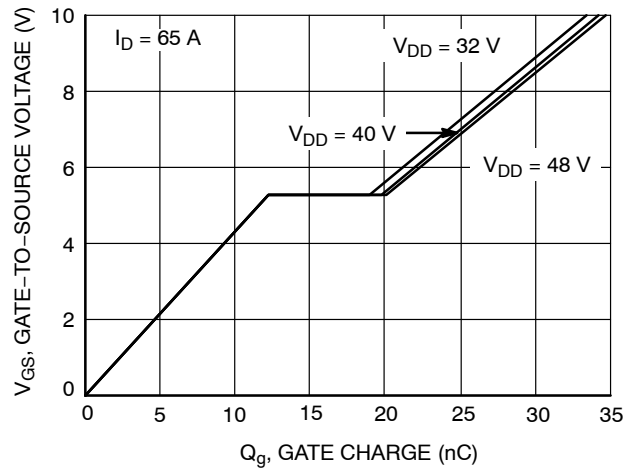
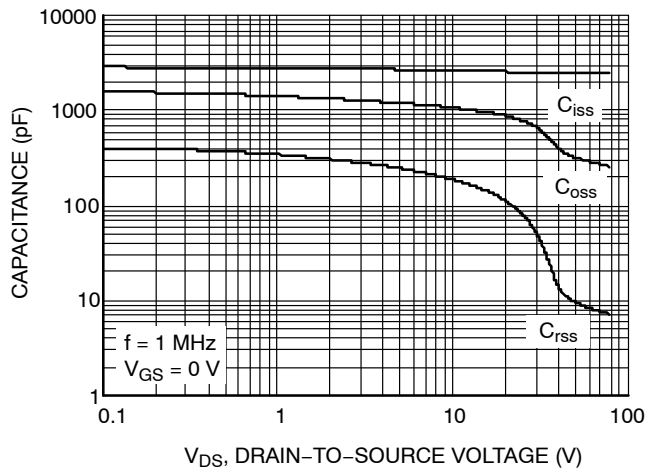
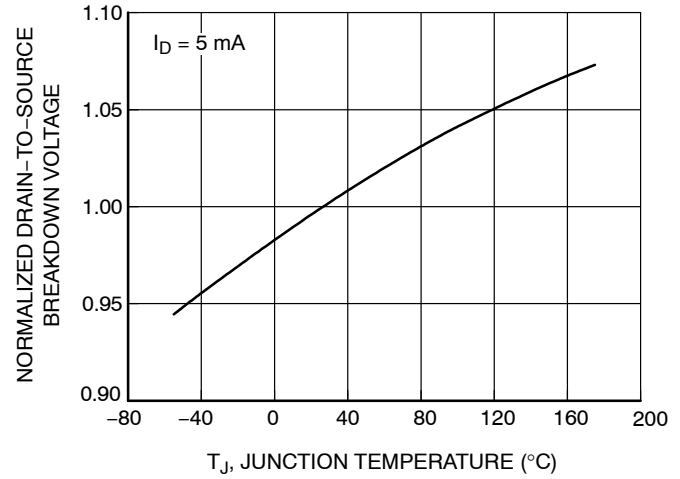
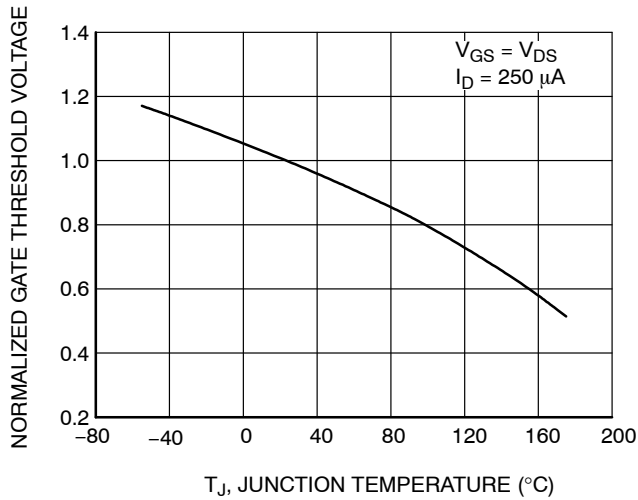
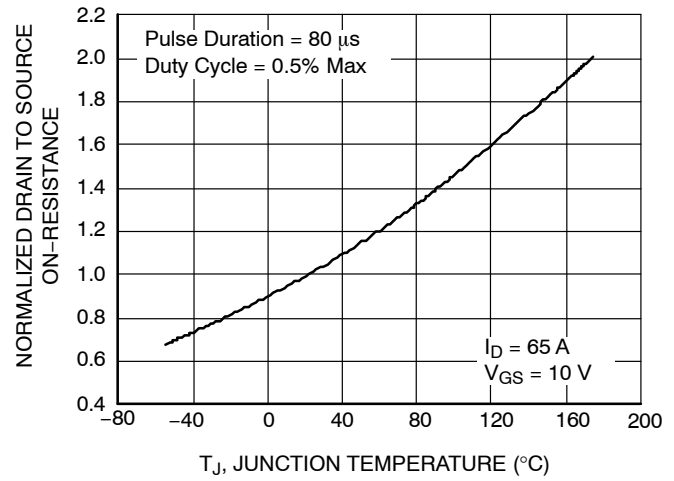
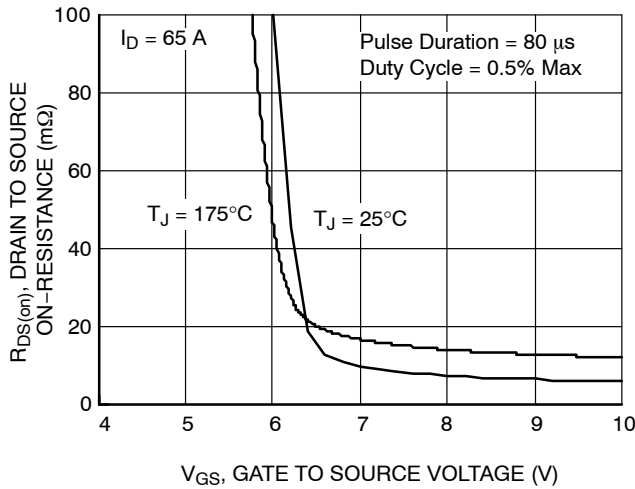
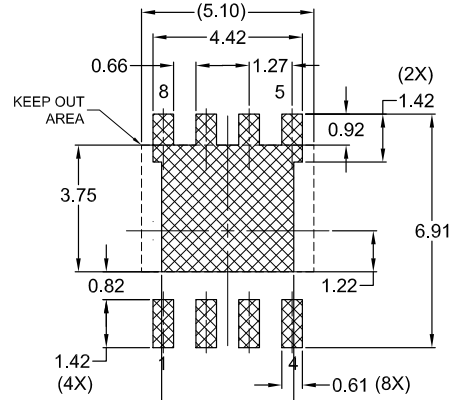
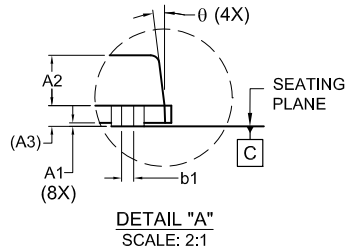
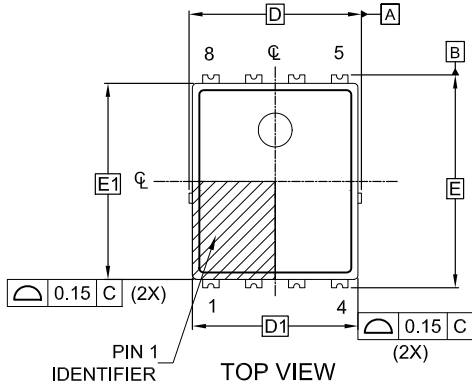


Figure 10. Saturation Characteristics

TYPICAL CHARACTERISTICS (continued)



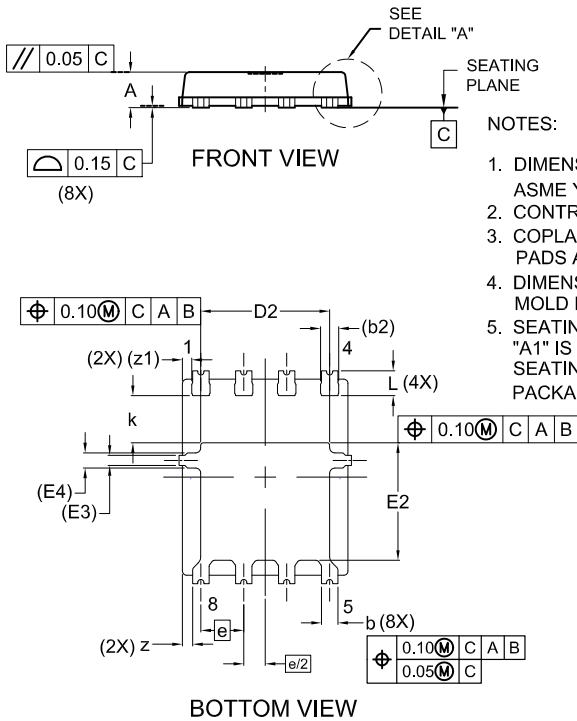
PACKAGE DIMENSIONS

DFNW8 5.2x6.3, 1.27P
CASE 507AU
ISSUE ALAND PATTERN
RECOMMENDATION

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. COPLANARITY APPLIES TO THE EXPOSED PADS AS WELL AS THE TERMINALS.
4. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
5. SEATING PLANE IS DEFINED BY THE TERMINALS. "A1" IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.



DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
A1	-	-	0.05
A2	0.65	0.75	0.85
A3	0.30 REF		
b	0.47	0.52	0.57
b1	0.13	0.18	0.23
b2	(0.54)		
D	5.00	5.10	5.20
D1	4.80	4.90	5.00
D2	3.72	3.82	3.92
E	6.20	6.30	6.40
E1	5.70	5.80	5.90
E2	3.38	3.48	3.58
E3	0.30 REF		
E4	0.45 REF		
e	1.27 BSC		
e/2	0.635BSC		
k	1.30	1.40	1.50
L	0.64	0.74	0.84
z	0.24	0.29	0.34
z1	(0.28)		
θ	0°	---	12°

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